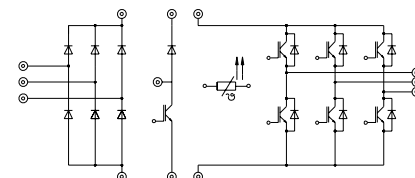


SKiiP 31 NAB 12 T11

Absolute Maximum Ratings			
Symbol	Conditions ¹⁾	Values	Units
Inverter	(Chopper see SKiiP 22 NAB 12 T18)		
V _{CEs}		1200	V
V _{GES}		± 20	V
I _C	T _{heatsink} = 25 / 80 °C	45 / 30	A
I _{CM}	t _p < 1 ms; T _{heatsink} = 25 / 80 °C	90 / 60	A
I _F = -I _C	T _{heatsink} = 25 / 80 °C	38 / 26	A
I _{FM} = -I _{CM}	t _p < 1 ms; T _{heatsink} = 25 / 80 °C	76 / 52	A
Bridge Rectifier			
V _{RRM}		1500	V
I _D	T _{heatsink} = 80 °C	35	A
I _{FSM}	t _p = 10 ms; sin. 180 °, T _J = 25 °C	700	A
I ² t	t _p = 10 ms; sin. 180 °, T _J = 25 °C	2400	A ² s
T _J		- 40 ... + 150	°C
T _{stg}		- 40 ... + 125	°C
V _{isol}	AC, 1 min.	2500	V

MiniSKiiP 3 SEMIKRON integrated intelligent Power SKiiP 31 NAB 12 T11 3-phase bridge rectifier + braking chopper 3-phase bridge inverter

Case M3



Characteristics					
Symbol	Conditions ¹⁾	min.	typ.	max.	Units
IGBT - Inverter					
V _{CEsat}	I _C = 30 A T _J = 25 (125) °C	-	2,5(3,1)	3,0(3,7)	V
t _{d(on)}	V _{CC} = 600 V; V _{GE} = ± 15 V	-	55	110	ns
t _r	I _C = 30 A; T _J = 125 °C	-	55	110	ns
t _{d(off)}	R _{gon} = R _{goff} = 39 Ω	-	400	600	ns
t _f	inductive load	-	45	90	ns
E _{on} + E _{off}		-	7,8	-	mJ
C _{ies}	V _{CE} = 25 V; V _{GE} = 0 V, 1 MHz	-	2,0	-	nF
R _{thjh}	per IGBT	-	-	0,7	K/W
IGBT - Chopper *					
V _{CEsat}	I _C = 15 A T _J = 25 (125) °C	-	2,5(3,1)	3,0(3,7)	V
t _{d(on)}	V _{CC} = 600 V; V _{GE} = ± 15 V	-	55	110	ns
t _r	I _C = 15 A; T _J = 125 °C	-	45	90	ns
t _{d(off)}	R _{gon} = R _{goff} = 82 Ω	-	400	600	ns
t _f	inductive load	-	70	100	ns
E _{on} + E _{off}		-	4,0	-	mJ
C _{ies}	V _{CE} = 25 V; V _{GE} = 0 V, 1 MHz	-	1,0	-	nF
R _{thjh}	per IGBT	-	-	1,4	K/W
Diode ²⁾ - Inverter (Diode ²⁾ - Chopper see SKiiP 22 NAB 12 T18)					
V _F = V _{EC}	I _F = 25 A T _J = 25 (125) °C	-	2,0(1,8)	2,5(2,3)	V
V _{TO}	T _J = 125 °C	-	1,0	1,2	V
r _T	T _J = 125 °C	-	32	44	mΩ
I _{RRM}	I _F = 25 A, V _R = - 600 V	-	25	-	A
Q _{rr}	di _F /dt = - 500 A/μs	-	4,5	-	μC
E _{off}	V _{GE} = 0 V, T _J = 125 °C	-	1,0	-	mJ
R _{thjh}	per diode	-	-	1,2	K/W
Diode - Rectifier					
V _F	I _F = 35 A T _J = 25 °C	-	1,2	-	V
R _{thjh}	per diode	-	-	1,6	K/W
Temperature Sensor					
R _{TS}	T = 25 / 100 °C		1000 / 1670		Ω
Mechanical Data					
M ₁	Mounting torque	2	-	2,5	Nm
Case			M3		

UL recognized file no. E63532

DataSheet4U.com

Options

- also available with powerful chopper. For characteristics please refer to Inverter IGBT

¹⁾ T_{heatsink} = 25 °C, unless otherwise specified

²⁾ CAL = Controlled Axial Lifetime Technology (soft and fast recovery)

* For diagrams of the Chopper IGBT please refer to SKiiP 22 NAB 12 T18

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.

SKiP 31 NAB 12 T11

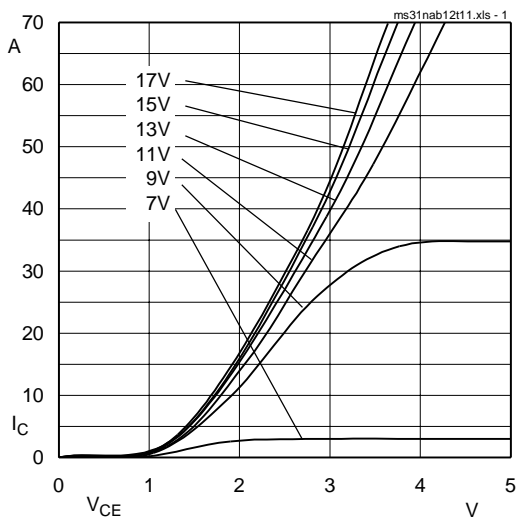


Fig. 1 Typ. output characteristic, $t_p = 80 \mu s$; $25 \text{ }^\circ\text{C}$

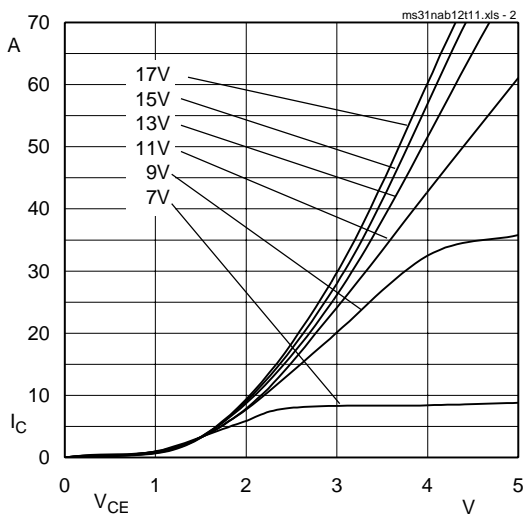


Fig. 2 Typ. output characteristic, $t_p = 80 \mu s$; $125 \text{ }^\circ\text{C}$

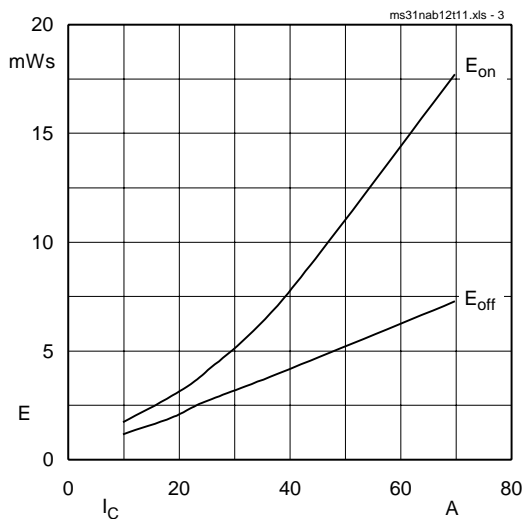


Fig. 3 Turn-on /-off energy = $f(I_c)$

$T_j = 125 \text{ }^\circ\text{C}$
 $V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_G = 39 \Omega$

Data

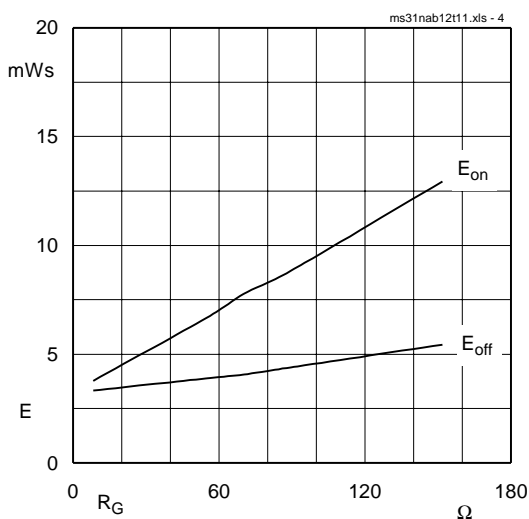


Fig. 4 Turn-on /-off energy = $f(R_G)$

$T_j = 125 \text{ }^\circ\text{C}$
 $V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_c = 35 \text{ A}$

DataSheet

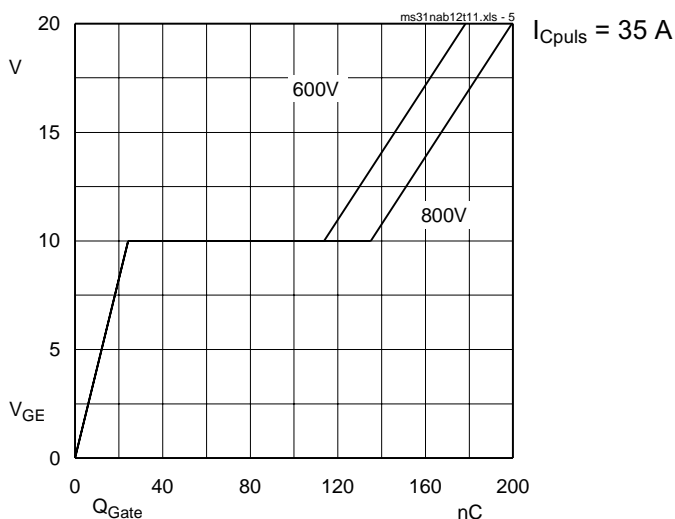


Fig. 5 Typ. gate charge characteristic

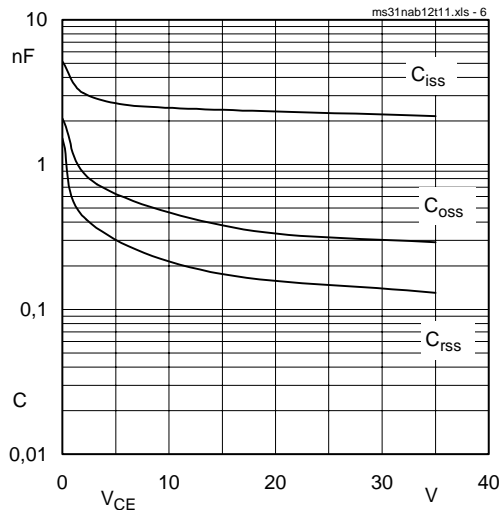


Fig. 6 Typ. capacitances vs. V_{CE}

$V_{GE} = 0 \text{ V}$
 $f = 1 \text{ MHz}$

MiniSKiiP 1200 V

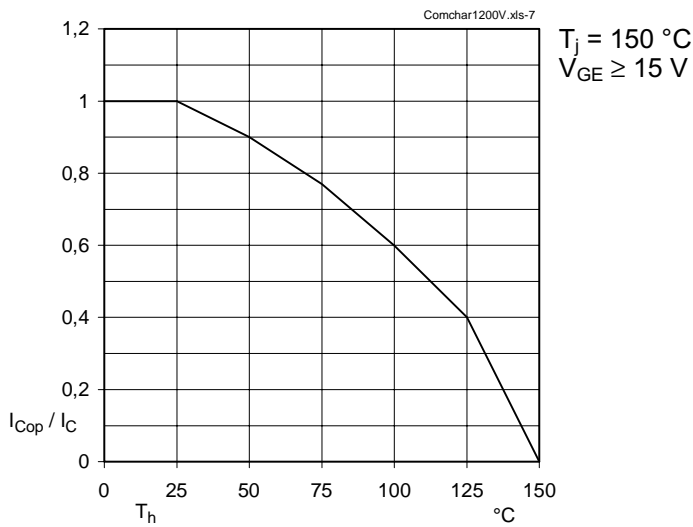


Fig. 7 Rated current of the IGBT $I_{C_{op}} / I_C = f(T_h)$

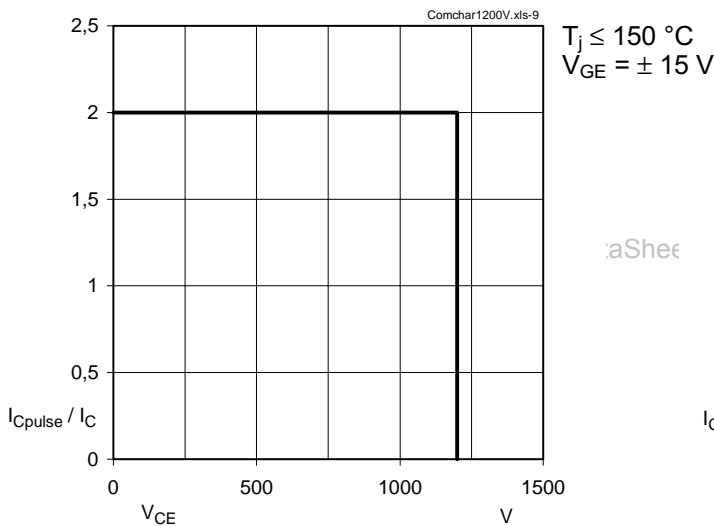


Fig. 9 Turn-off safe operating area (RBSOA) of the IGBT

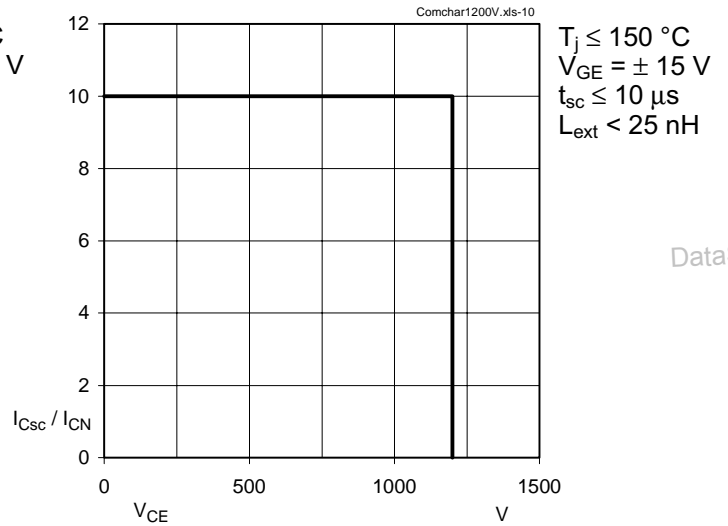


Fig. 10 Safe operating area at short circuit of the IGBT

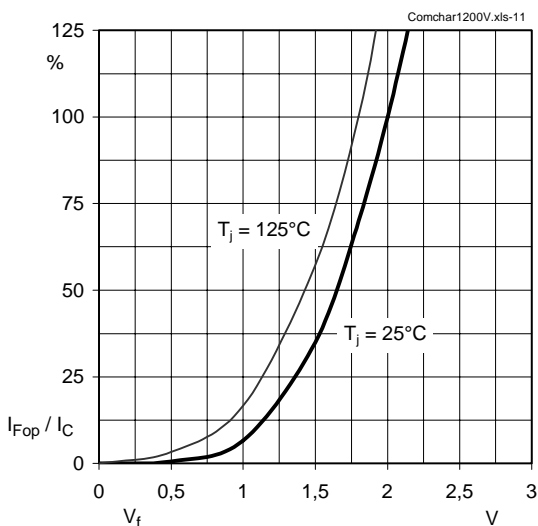


Fig. 11 Typ. freewheeling diode forward characteristic

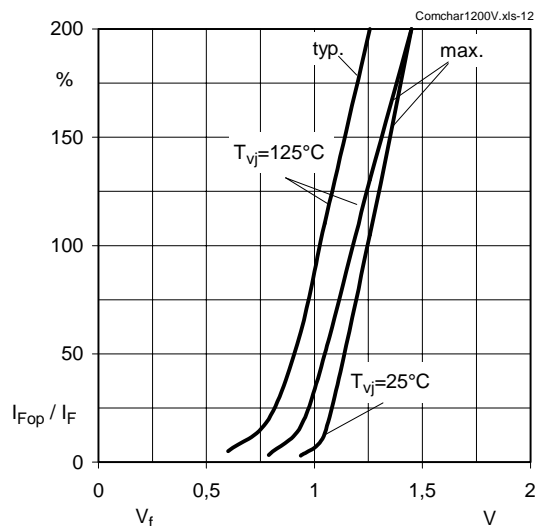
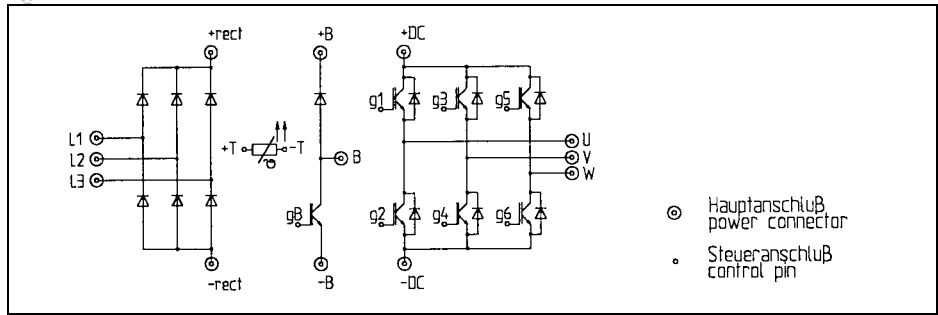


Fig. 12 Forward characteristic of the input bridge diode

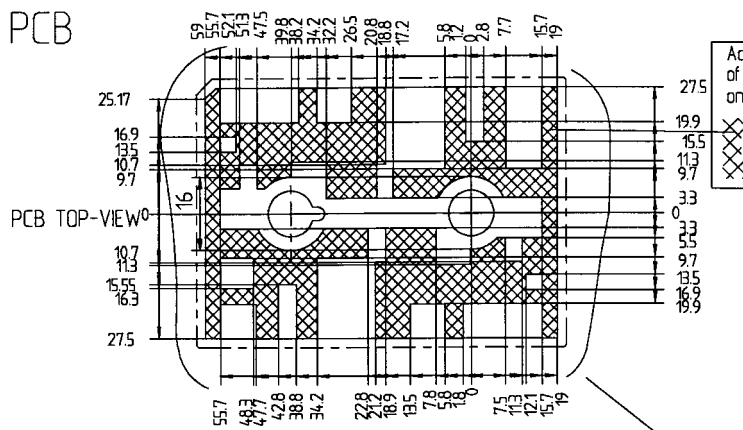
MiniSKiiP 3

- SKiiP 30 NAB 12 T10
- SKiiP 31 NAB 12 T11
- SKiiP 32 NAB 12 T1



- ⊕ Hauptanschluß power connector
- Steueranschluß control pin

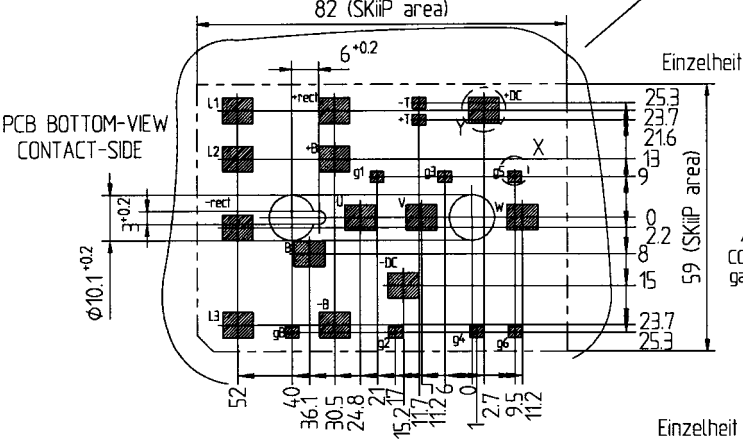
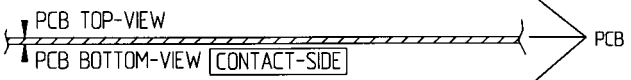
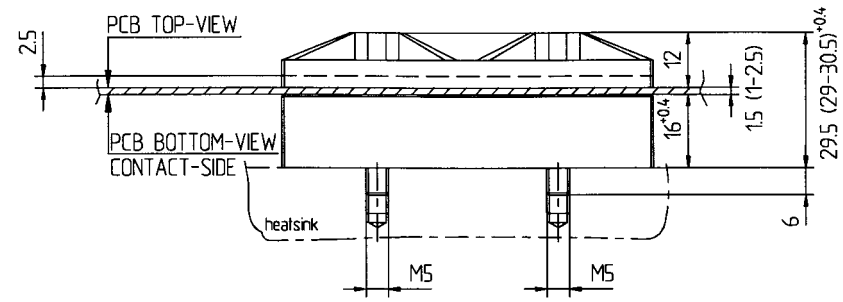
PCB



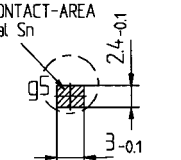
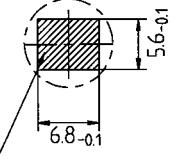
Accessible for mounting of SMD (max height 2.5) on PCB (by customer).

⊗ mounting area

Mini-SKiiP 3

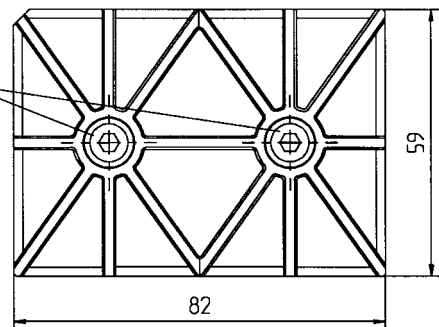


Einzelheit "Y" Maßstab 2 : 1



Einzelheit "X" Maßstab 2 : 1

Bitte beachten Sie die Montagevorschrift
For mounting please follow the assembly instruction



Tolerance: ISO 2768-f